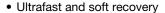


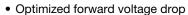
Ultrafast Rectifier, 30 A FRED Pt®

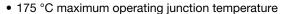


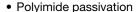
PRIMARY CHARACTERISTICS						
I _{F(AV)} 30 A						
V_{R}	1200 V					
V _F at I _F at 125 °C	2.05 V					
t _{rr}	49 ns					
T _J max.	175 °C					
Package	2L TO-220AC					
Circuit configuration	Single					

FEATURES









· Rugged design

· Good thermal performance

• Meets JESD 201 class 2 whisker test

Material categorization: for definitions of compliance



RoHS COMPLIANT

HALOGEN FREE

please see	www.vishay.com/doc?99912	

DESCRIPTION / APPLICATIONS

Ultrafast recovery rectifiers designed with optimized performance of forward voltage drop, recovery time, and soft recovery. Polyimide passivated, planar structure, and the platinum doped life time control guarantee, ruggedness, reliability characteristics, and solid value proposition for efficiency and thermal performance.

These devices are intended for use in boost stage in the AC/DC section of SMPS, high frequency output rectification of battery charger, inverters for solar inverters, or as freewheeling diodes in motor drive.

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V_{RRM}		1200	V				
Average rectified forward current	I _{F(AV)}	T _C = 100 °C, D = 0.50	30	Α				
Repetitive peak forward current	I _{FRM}		60	Α				
Non-repetitive peak surge current	I _{FSM}	T_C = 25 °C, t_p = 10 ms, sine wave	240	Α				
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS MIN. TYP.				UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 500 μΑ	1200	-	-		
	V _F	I _F = 30 A	-	2.15	2.68	V	
Forward voltage		I _F = 30 A, T _J = 125 °C	-	2.05	2.45		
Dovers leskage current		$V_R = V_R$ rated	-	-	145		
Reverse leakage current	I _R	T _J = 125 °C, V _R = V _R rated	-	-	320	μA	
Junction capacitance	C _T	V _R = 200 V	-	29	-	pF	
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH	



DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CO	NDITIONS	MIN.	TYP.	MAX.	UNITS
		$I_F = 1.0 \text{ A}, dI_F/dt = 10$	00 A/μs, V _R = 30 V	-	49	-	
Reverse recovery time	t _{rr}	T _J = 25 °C	$I_F = 30 \text{ A}$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$ $V_R = 390 \text{ V}$	-	220	-	ns
		T _J = 125 °C		-	356	-	
Dools we construct on which		T _J = 25 °C		-	8.2	-	^
Peak recovery current	I _{RRM}	T _J = 125 °C		-	13.3	-	Α
Davide de la constant	0	T _J = 25 °C		-	900	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	2388	-	nC

THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Thermal resistance, junction to case	R _{thJC}		-	-	0.8		
Thermal resistance, junction to ambient	R _{thJA}	Typical socket mount	-	-	54	°C/W	
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	-	0.4		
Weight			-	0.2	-	g	
Weight			-	0.07	-	oz.	
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)	
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C	
Marking device		Case style: 2L TO-220AC		30ET	U12T		

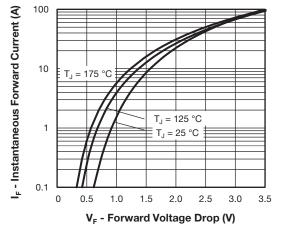


Fig. 1 - Typical Forward Voltage Drop Characteristics

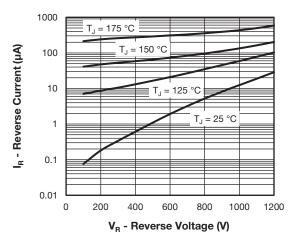


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

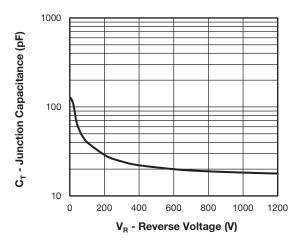


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

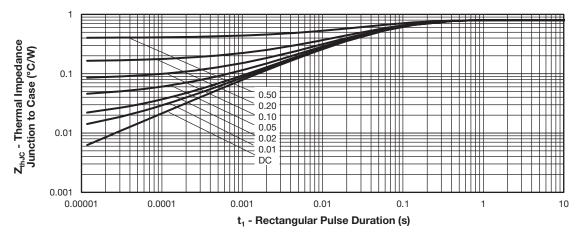


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

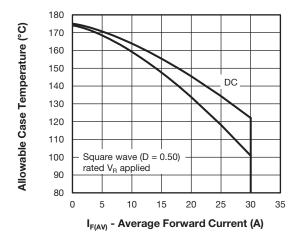


Fig. 5 - Maximum Allowable Case Temperature vs.
Average Forward Current

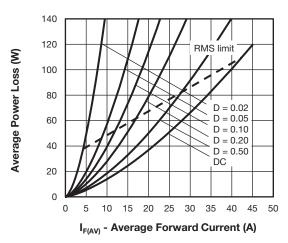


Fig. 6 - Forward Power Loss Characteristics

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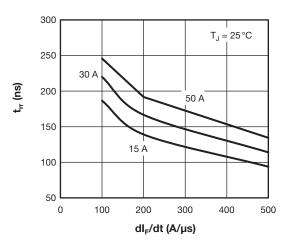


Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt

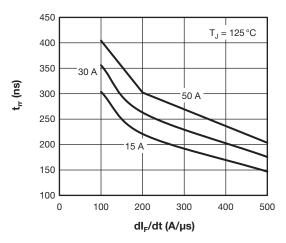


Fig. 8 - Typical Reverse Recovery Time vs. dl_F/dt

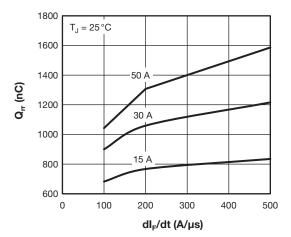


Fig. 9 - Typical Stored Charge vs. dl_F/dt

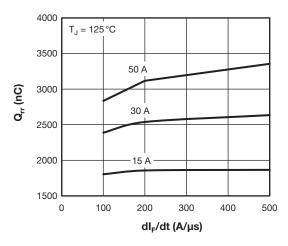


Fig. 10 - Typical Stored Charge vs. dl_F/dt

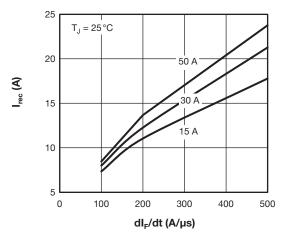


Fig. 11 - Typical Reverse Current vs. dl_F/dt

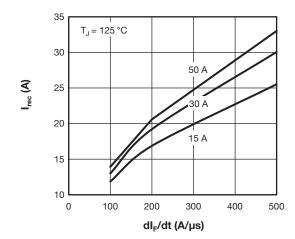
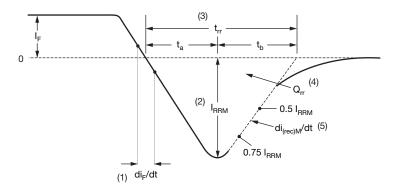


Fig. 12 - Typical Reverse Current vs. dl_F/dt



- (1) di_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM} extrapolated to zero current.
- (4) $\rm Q_{rr}$ area under curve defined by $\rm t_{rr}$ and $\rm I_{BBM}$

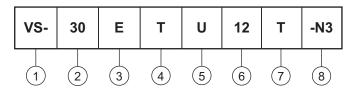
$$Q_{rr} = \frac{t_{rr} x I_{RRM}}{2}$$

(5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

Fig. 13 - Reverse Recovery Waveform and Definitions

ORDERING INFORMATION TABLE

Device code



- Vishay Semiconductors product
- Current rating 30 = 30 A
- 3 E = single diode
- 4 Package: T = TO-220AC
- 5 U = ultrafast recovery
- 6 Voltage rating (12 = 1200 V)
- 7 T = True 2 pin TO-220
- 8 Environmental digit:

-N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

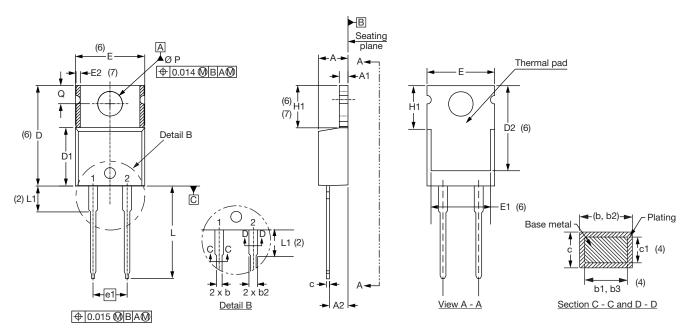
ORDERING INFORMATION (Example)							
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION				
VS-30ETU12T-N3	50	1000	Antistatic plastic tube				

LINKS TO RELATED DOCUMENTS					
Dimensions	2L TO-220AC	www.vishay.com/doc?96069			
Part marking information	2L TO-220AC	www.vishay.com/doc?95391			



2L TO-220AC

DIMENSIONS in millimeters and inches



SYMBOL	MILLIM	IETERS	INCHES		NOTES
STIMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.25	4.65	0.167	0.183	
A1	1.14	1.40	0.045	0.055	
A2	2.56	2.92	0.101	0.115	
b	0.69	1.01	0.027	0.040	
b1	0.38	0.97	0.015	0.038	4
b2	1.20	1.73	0.047	0.068	
b3	1.14	1.73	0.045	0.068	4
С	0.36	0.61	0.014	0.024	
c1	0.36	0.56	0.014	0.022	4
D	14.85	15.25	0.585	0.600	3
D1	8.38	9.02	0.330	0.355	
D2	11.68	12.88	0.460	0.507	6
Е	10.11	10.51	0.398	0.414	3, 6

SYMBOL	MILLIMETERS		INCHES					NOTES
STWIDOL	MIN.	MAX.	MIN.	MAX.	NOTES			
E1	6.86	8.89	0.270	0.350	6			
E2	-	0.76	-	0.030	7			
е	2.41	2.67	0.095	0.105				
e1	4.88	5.28	0.192	0.208				
H1	6.09	6.48	0.240	0.255	6, 7			
L	13.52	14.02	0.532	0.552				
L1	3.32	3.82	0.131	0.150	2			
ØΡ	3.54	3.73	0.139	0.147				
Q	2.60	3.00	0.102	0.118				

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- (5) Controlling dimension: inches
- (6) Thermal pad contour optional within dimensions E, H1, D2 and E1
- (7) Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- (8) Outline conforms to JEDEC® TO-220, except D2, where JEDEC® minimum is 0.480".

Legal Disclaimer Notice



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